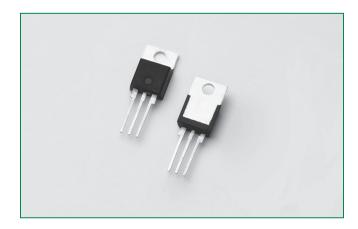
# SK625xD Series





#### **Description**

Excellent unidirectional switches for phase control applications such as heating and motor speed controls.

Standard phase control SCRs are triggered with few milliamperes of current at less than 1.5V potential.

### **Features & Benefits**

- RoHS compliant
- Voltage capability up to 1600 V
- Surge capability up to 250 A

 Electrically isolated package "LD-Package" and UL recognized for 2500V<sub>RMS</sub>

## **Agency Approval**

Agency	Agency File Number
<b>71</b>	E71639

### **Applications**

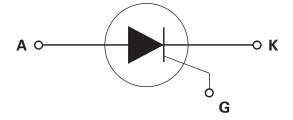
Typical applications are AC solid-state switches, industrial power tools, line rectification 50/60Hz.

Internally constructed isolated packages are offered for ease of heat sinking with highest isolation voltage.

### **Main Features**

Symbol	Value	Unit
I <sub>T(RMS)</sub>	25	А
V <sub>DRM</sub> /V <sub>RRM</sub>	1600	V
I <sub>GT</sub>	35	mA

### **Schematic Symbol**



# Absolute Maximum Ratings — 25A SCR

Symbol	Parameter	Test Conditions		Value	Unit
$V_{DRM}/V_{RRM}$	Repetitive Peak off-state/Reverse Voltage			1600	V
$V_{DSM}/V_{RSM}$	Non-repetitive peak off-state/Reverse voltage			1700	V
1	RMS on-state current	SK625LD	T <sub>C</sub> = 60°C	25	А
T(RMS)	THIVIS OIT-State Current	SK625RD	T <sub>C</sub> = 90°C	25	
	Average on state current	SK625LD	$T_{\rm C} = 60^{\circ}{\rm C}$	16	А
T(AV)	Average on-state current	SK625RD	T <sub>C</sub> = 90°C	10	
	Peak non-repetitive surge current		single half cycle; $f = 50Hz$ ; $T_J$ (initial) = $25^{\circ}C$		А
<sup>I</sup> TSM			vcle; f = 60Hz; l) = 25°C	300	
l²t	l²t Value for fusing	$t_p = 8$	3.3 ms	375	A <sup>2</sup> s
di/dt	Critical rate of rise of on-state current			100	A/µs
I <sub>GM</sub>	Peak gate current	T <sub>J</sub> = 125°C		1.5	А
P <sub>G(AV)</sub>	Average gate power dissipation	T <sub>J</sub> = 125°C		1	W
T <sub>stg</sub>	Storage temperature range	-40 to 150	°C		
T	Operating junction temperature range			-40 to 125	°C

Notes : x = package

## **Electrical Characteristics** (T<sub>J</sub> = 25°C, unless otherwise specified)

Symbol	Test Conditions	Value	Unit	
I <sub>GT</sub>	V = 12V: B = 200	MAX.	35	mA
V <sub>GT</sub>	$V_D = 12V; R_L = 30\Omega$	MAX.	1.5	V
dv/dt	$V_D = 2/3 V_{DRM}$ ; gate open; $T_J = 125$ °C	MIN.	2000	V/µs
$V_{\rm GD}$	$V_{D} = V_{DRM}$ ; $R_{L} = 3.3 \text{ k}\Omega$ ; $T_{J} = 125^{\circ}\text{C}$	MIN.	0.2	V
I <sub>H</sub>	$I_{T} = 500 \text{mA (initial)}$	MAX.	120	mA
t <sub>q</sub>	I <sub>T</sub> =0.5A; t <sub>p</sub> =50μs; dv/dt=5V/μs; di/dt=-30A/μs	TYP.	25	μs
t <sub>gt</sub>	$I_{G} = 2 \times I_{GT}$ , PW = 15 $\mu$ s; $I_{T} = 50A$	TYP.	5	μs

Notes : x = package

## **Static Characteristics**

Symbol	Test Conditions			Value	Unit
V <sub>TM</sub>	$I_{T} = 50A; t_{p} = 380 \mu s$	1.8	V		
1 /1	V IV	T <sub>J</sub> = 25°C	NAAV	10	μА
I <sub>DRM</sub> / I <sub>RRM</sub> V <sub>DRM</sub> / V <sub>RRM</sub>	T <sub>J</sub> = 125°C	MAX.	4	mA	

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Symbol	Parameter		Value	Unit
D	lunction to cook (AC)	SK625RD	1.0	°C/W
Π <sub>θ(J-C)</sub>	Junction to case (AC)	SK625LD	1.9	- C/VV

Figure 1: Normalized DC Gate Trigger Current vs. Junction Temperature

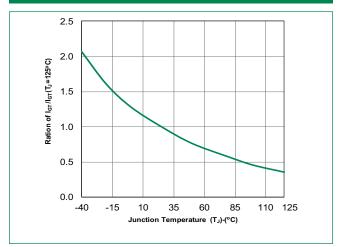


Figure 3: Normalized DC Holding Current vs. Junction Temperature

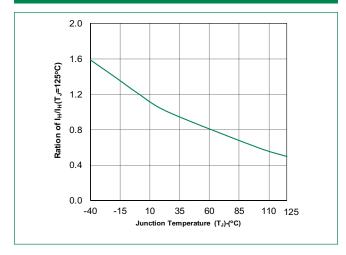


Figure 5: Power Dissipation (Typical) vs. RMS On-State Current

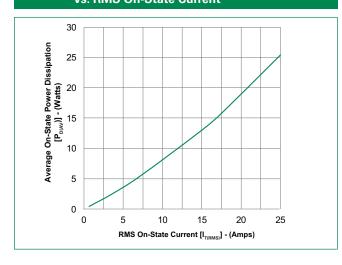


Figure 2: Normalized DC Gate Trigger Voltage vs. Junction Temperature

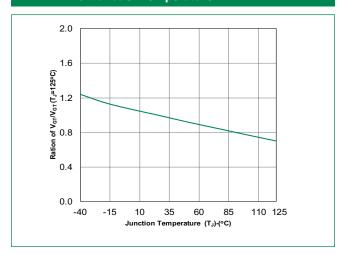


Figure 4: On-State Current vs. On-State Voltage (Typical)

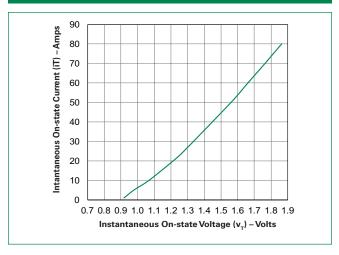


Figure 6: Maximum Allowable Case Temperature vs. RMS On-State Current

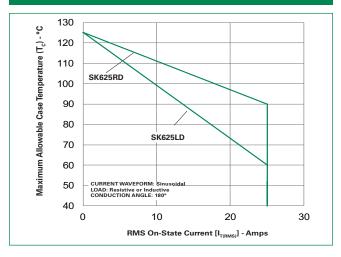


Figure 7: Maximum Allowable Case Temperature vs. Average On-State Current

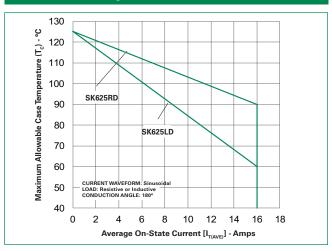
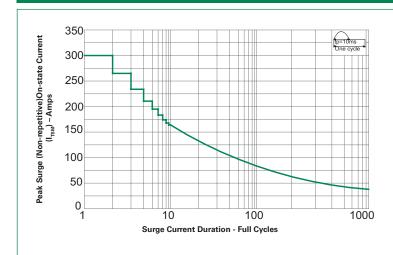


Figure 8: Surge Peak On-State Current vs. Number of Cycles



SUPPLY FREQUENCY: 50 Hz Sinusoidal

LOAD: Resistive

RMS On-State Current:  $[I_{T(RMS)}]$ : Maximum Rated Value at Specified Case Temperature

#### Notes:

- 1. Gate control may be lost during and immediately following surge current interval.
- 2. Overload may not be repeated until junction temperature has returned to steady-state rated value.

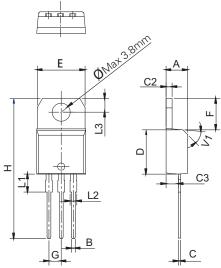
### **Environmental Specifications**

Test	Specifications and Conditions
AC Blocking	JESD22-A108C, 80% V <sub>DRM</sub> @125°C for 168 hours
Temperature Cycling	MIL-STD-750, M-1051, 100 cycles; -40°C to +150°C; 15-min dwell-time
Temperature/ Humidity	EIA / JEDEC, JESD22-A101 168 hours; 100V - DC: 85°C; 85% rel humidity
Resistance to Solder Heat	JESD22-B106C
Solderability	J-STD-022, category 3, test A

## **Design Considerations**

Careful selection of the correct device for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the device rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

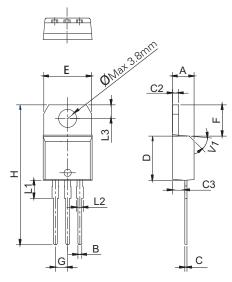
## Dimensions — TO-220AB (RD-Package) — Non-Isolated Mounting Tab Common with Center Lead



Note: Maximum torque to be applied to mounting tab is 3 in-lbs (0.3Nm).

Dimension	N	Millimeters Inches				
Dimension	Min.	Тур.	Max.	Min.	Тур.	Max.
А	4.40		4.60	0.173		0.181
В	0.61		0.88	0.024		0.035
С	0.46		0.70	0.018		0.028
C2	1.21		1.32	0.048		0.052
C3	2.40		2.72	0.094		0.107
D	8.60		9.70	0.339		0.382
Е	9.60		10.4	0.378		0.409
F	6.20		6.60	0.244		0.260
G		2.54			0.1	
Н	28.0		29.8	1.102		1.173
L1		3.75			0.148	
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116
V1		45°			45°	

## Dimensions — TO-220AB (LD-Package) — Isolated Mounting Tab



Note: Maximum torque to be applied to mounting tab is 7 in-lbs. (0.8 Nm).

Dimension	IV	lillimeters	3		Inches	
Difficusion	Min.	Тур.	Max.	Min.	Тур.	Max.
А	4.40		4.60	0.173		0.181
В	0.61		0.88	0.024		0.035
С	0.46		0.70	0.018		0.028
C2	1.21		1.32	0.048		0.052
C3	2.40		2.72	0.094		0.107
D	8.60		9.70	0.339		0.382
Е	9.80		10.4	0.386		0.409
F	6.55		6.95	0.258		0.274
G		2.54			0.1	
Н	28.0		29.8	1.102		1.173
L1		3.75			0.148	
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116
V1		45°			45°	

### **Product Selector**

Part Number	Gate Sensitivity	Туре	Package
SK625LD	35mA	Standard SCR	TO-220L
SK625RD	35mA	Standard SCR	TO-220R

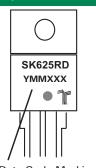
## **Packing Options**

Part Number	Marking	Weight	Packing Mode	Base Quantity
SK625LDTP	SK625LD	2.2g	Tube	1000
SK625RDTP	SK625RD	2.0g	Tube	1000

# Part Numbering System



# **Part Marking System**



Date Code Marking Y:Year Code MM: Month Code XXX: Lot Trace Code